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Segregation of Mg at $TiB₂/Al$ interface mitigating the Zr-poisoning effect

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ABSTRACT

Interfacial segregation can modify a substrate's heterogeneous-nucleation potency. In Al alloys inoculated with TiB2, for instance, Zr segregation degrades TiB2's nucleation potency and causes the loss of grain refinement, a phenomenon termed the Zr-poisoning effect. Here we use grain-refining tests to demonstrate that the addition of Mg can revive grain refinement from the Zr-poisoning effect. Using advanced transmission electron microscopy, we identify the segregation of Mg at the TiB₂/Al interface, which causes the disappearance of the poisoning Ti₂Zr two-dimensional compound (2DC). In its place, atomic layers of a nature close to the Al solid, which we term "Allike layers", develop, rendering the TiB₂ potent again to catalyse the nucleation of α -Al. Thereby, Mgsegregation-modified TiB₂ particles are reactivated for heterogeneous nucleation of Al grains. Apart from a mitigation of the Zr-poisoning effect, this work may shed further light on the manipulation of heterogeneous nucleation by atomic engineering of the nucleating substrate.

Main

Grain refinement is essential in aluminium (Al) alloys for improvements in aspects of casting integrity, alloy microstructure, mechanical properties, and processability for downstream thermomechanical processing [1–[3\]](#page-5-0). To obtain grain refinement, chemical inoculation is the most practical and widely used method in Al foundries, for which Al-5Ti-1B master alloy is one of the most successful grain refiners developed over many decades [\[4,5\]](#page-5-0). Despite its practical success, the mechanism underpinning its effectiveness has been disputed for a long time; several theories were proposed, with no clear consensus emerging $[6–14]$ $[6–14]$ $[6–14]$. The advent of advanced (scanning) transmission electron microscopy (S/TEM) in combination with powerful computational methods has offered unprecedented insights into the mechanism and its roots at the TiB2/Al interface: it identified the so-called Al3Ti 2DC as a key interfacial segregation layer that modifies $TiB₂$ and enhances its potency to nucleate α-Al grains $[14–18]$ $[14–18]$. Such interface can be further manipulated by the segregation of Zr or Si, which was revealed as the cause of observed Zr- and Si-poisoning effects [\[19](#page-5-0)–21]. Realising the importance of TiB₂/Al interfaces, Li *et al.* intentionally doped TiB₂ particles with solute C, the segregation of which turned out to greatly remove the Si- and Zr- poisoning effects [[22\]](#page-5-0). Thus, a general concept of atomic engineering of the substrate/metal interface emerges as a strategy to manipulate heterogeneous nucleation by modifying the structural and chemical compatibility at the interface. This has now also been realised in substrate/metal systems other than TiB2/Al, such as MgO/Mg [23–[25\]](#page-5-0), γAl₂O₃/Al [\[24](#page-5-0)–26], and αAl₂O₃/Al [\[27,28](#page-5-0)], to alter accordingly the heterogeneous nucleation behaviour.

Grain-refining test results in the literature suggest that, like C, Mg could be a solute candidate to alleviate the Zr-poisoning effect through atomic-level engineering of interfacial segregation. It was observed by Birch and Fisher that Mg can counteract the Zr-poisoning effect [\[29](#page-5-0)]. And in contrast to the catastrophic loss of grain refinement in commercial purity (CP) Al [\[19\]](#page-5-0), Al-5Zn-1.5Mg, AA7050 and AA7055 alloys were shown to experience a relatively mild Zr-poisoning effect [[30,31](#page-5-0)]. Similarly, the addition of 0.13 wt.% Zr into both Al-2.5Cu-2.5Mg and Al-6.5Zn-2.5Mg with 0.2 wt.% Al-3Ti-1B inoculation only caused small increases in grain size [[32\]](#page-5-0). Although these Al alloys all contain Mg, we cannot conclude from a sole heterogeneous nucleation perspective that the interfacial segregation of Mg rejuvenates $TiB₂$ substrates' potency. An alternative explanation could be that the solute's contribution to growth restriction acts as the dominant factor mitigating the

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Zr-poisoning effect. Both mechanisms may also work synergistically. More experimental work is therefore required to verify the role of Mg. This motivated the present work to answer the following questions: *i)* does the addition of Mg revive grain refinement from the Zr-poisoning effect? *ii*) can Mg segregate to the TiB₂/Al interface? *iii*) what is the atomic modification at the interface, if any? *iv)* how is heterogeneous nucleation modified? And *v)* what is the mechanism of grain refinement?

Experimental methods are provided in the supplementary material. The raw materials and master alloys are given in Table S1. To study the effect of alloy compositions (in wt.% unless otherwise specified) on the performance of Al-5Ti-1B, a series of grain refining tests were carried out, with samples listed in Table S2. Each test sample was named according to the added materials and their sequences in the casting experiments. Electron microscopy was used post-mortem to investigate any atomic modifications at the TiB2/Al interface for which the changes in grain refining performance were observed. TEM specimens were prepared from the representative samples: Al-0.2Al5Ti1B, Al-0.1Zr-0.2Al5Ti1B, and Al-0.1Zr-0.2Al5Ti1B-1Mg.

Fig. 1 demonstrates as a control experiment the now well-known effects of interfacial segregation on the grain-refining capability of TiB₂ inoculation. As expected, the addition of 0.2 % Al-5Ti-1B drastically refines the grain structure of CP Al after solidification (Fig. 1(a)), which is attributed to the exceeding nucleation potency of the added TiB₂ particles that have an Al₃Ti 2DC segregation layer on their basal surface $([17], Fig. 1(d))$ $([17], Fig. 1(d))$ $([17], Fig. 1(d))$. In contrast, a poisoning effect occurs when 0.1Zr is present in the melt, as coarse and columnar grains appear in the solidified Al-0.1Zr-0.2Al5Ti1B ingot (Fig. 1(b)). As shown by the high-angle annular dark field (HAADF) STEM image in Fig. 1(e), Zr is found concentrated at the interface between the TiB₂ basal plane and Al (quoted as TiB2/Al unless specified otherwise), forming the so-called Ti₂Zr 2DC monolayer $[19]$ $[19]$ that poisons the potency of TiB₂. Strinkingly, a further addition of 1 % Mg appears to counteract the Zr-posoning effect, reviving grain refinement in the cast sample of Al-0.1Zr-0.2Al5Ti1B-1Mg (Fig. 1(c)). At the corresponding $TiB₂/Al$ interface, neither Al₃Ti 2DC nor Ti₂Zr 2DC is observed (Fig. 1(f)). Two atomic layers of faint contrast are found instead. Further STEM-EDS mapping in Fig. $1(g)$ finds that they are spatially correlated to the areas where Mg is concentrated whilst the segregation of Zr at the interface disappears. A possible conclusion is thus that Mg can segregate to the TiB2/Al interface and restore grain refinement in Al-0.1Zr-0.2Al5Ti1B-1Mg from the Zr-poisoning effect.

More grain-refining-test results in Figs. S1 and S2 indicate that either the Zr-poisoning or the mitigation behaviour is not affected by the addition sequence. When grain refinement is regained, $TiB₂$ particles were repeatedly observed within Al grains (around 200 μm on average) in Al-0.1Zr-0.2Al5Ti1B-1Mg, with an example shown in Fig. S3. The $TiB₂$ particles remain as hexagonal plates in morphology and follow a log-normal size distribution (Fig. S4). In comparison with previous reports [\[17,19,33](#page-5-0),[34\]](#page-5-0), additions of 0.1 % Zr and 1 % Mg into the Al melt

Fig. 1. Mitigation of Zr-poisoning by the interfacial segregation of Mg at the TiB2/Al interface. (a-c) Optical macrographs of (a) Al-0.2Al5Ti1B; (b) Al-0.1Zr-0.2Al5Ti1B; and (c) Al-0.1Zr-0.2Al5Ti1B-1Mg. (d-f) HAADF STEM images showing the interfacial segregation layer(s) at the TiB2/Al interfaces in the corresponding samples of (a-c), as viewed along the < $11\overline{20}$ >_{TiB2} zone axis. (g) Segregation of Mg illustrated by STEM-EDS elemental maps of Ti (g1), Zr (g2), Al (g3), Mg (g4), and Fe (g5) across the TiB₂/Al interface in sample Al-0.1Zr-0.2Al5Ti1B-1Mg.

do not affect the shape and size of $TiB₂$ particles. Moreover, the previous work $[19]$ $[19]$ showed that, once TiB_2 becomes impotent due to the Zr-poisoning, increasing the growth restriction can not refine the solidified grains. By excluding these factors, we posit that the atomic-scale modification at the TiB2/Al interface accounts for the grain-refining behaviour depicted in [Fig.](#page-1-0) 1.

Fig. 2(a-c) readily shows striking microstructural differences in the atomic-resolution HAADF STEM images across TiB₂/Al interfaces among the three samples: the control Al-0.2Al5Ti1B, the poisoned Al-0.1Zr-0.2Al5Ti1B, and the rejuvenated Al-0.1Zr-0.2Al5Ti1B-1Mg.

In Al-0.2Al5Ti1B, a monolayer of Al_3Ti 2DC is seen at the TiB₂/Al interface (Fig. $2(a)$), exhibiting a slightly lower brightness than the Ti columns in the $TiB₂$ matrix. Above this, another two less-intense atomic layers (labelled #12–13, the second being more diffuse) are observed. They are assumed to be mainly comprised of Al, which would be inherited from liquid layering during prenucleation [\[18,35](#page-5-0),[36\]](#page-5-0). Similar atomic layering features can be recognised in the results from prior reports, albeit not identified nor explicitly commented on [[17,21,22](#page-5-0)]. Furthermore, in another system, a similar structure of Al-transition layers was reported at the TiC_y/Al interface [[37\]](#page-5-0). Unlike the Ti atomic layers in TiB₂, which stack coincidently along the $[0001]_{TIB2}$ axis, the Al3Ti 2DC monolayer shifts to a different lattice site. From this Ti-rich layer upward, the atomic layers (#11–13) stack in a manner following the face-centered-cubic (FCC) type. The interplanar spacing (*d*-spacing) was measured for each labelled layer as the distance to the layer

beneath. As shown in Fig. 2(a1), the *d*-spacings are 0.208 ± 0.011 nm and 0.214 ± 0.021 nm for layer #12 and #13, respectively. As suggested by the larger error bars, they have a lower degree of in-plane order than that of the $TiB₂$ matrix.

In the poisoned Al-0.1Zr-0.2Al5Ti1B, however, the Al₃Ti 2DC disappears and the Ti2Zr 2DC forms instead as the result of Zr interfacial segregation (Fig. 2(b)). In the Ti₂Zr 2DC monolayer (#10), Zr atoms occupy the Ti sites of TiB₂ with positional deviation, appearing as elliptical columns of higher brightness than the pure Ti columns. Here, a dull atomic layer #11 not obeying the FCC stacking sequence appears 0.184 \pm 0.007 nm above the Zr-rich layer (Fig. 2(b1)), which could be an Al-based atomic layer indicated by the image contrast. Further into the Al matrix, the contrast becomes too diffuse to be recognized as ordered atomic layers.

These results confirm once more that by tuning nucleation potency, the formation of Al₃Ti 2DC accounts for the grain refinement (Fig. [1\(a\)](#page-1-0)), while Ti₂Zr 2DC causes the poisoning effect (Fig. $1(b)$). These findings are consistent with previous studies on this system [[14](#page-5-0),[17,19\]](#page-5-0).

After further adding 1 % Mg (*i.e.,* Al-0.1Zr-0.2Al5Ti1B-1Mg, Fig. 2 (c)), the Ti₂Zr 2DC disappears but the Al₃Ti 2DC is not regained at the TiB₂/Al interface. Instead, two clearly visible atomic layers (labelled $#11-12$) and another layer of faint contrast ($#13$) appear. Similar to the atomic layers beyond Al3Ti 2DC described above, their stacking pattern changes into an FCC-type sequence. As shown in Fig. $2(c1)$, the measured *d*-spacings are 0.205 ± 0.008 nm for layer #11 and $0.203 \pm$

Fig. 2. (a-c) Atomic-resolution HAADF STEM images showing the atomic structure across the TiB2/Al interface in samples (a) Al-0.2Al5Ti1B; (b) Al-0.1Zr-0.2Al5Ti1B; and (c) Al-0.1Zr-0.2Al5Ti1B-1Mg. (a1-c1) The corresponding interplanar spacings across the interface are statistically measured by Atomap [\[38\]](#page-5-0). In an interested atomic layer the spacing between every atomic column to the layer underneath is measured to gain average values and statistical errors for the interplanar spacing. (d-e) HAADF STEM images and EELS elemental maps showing the distribution of (d) Mg, (e) Ti, B, Al across the TiB2/Al interface in sample Al-0.1Zr-0.2Al5Ti1B-1Mg. The incident beam is parallel to the $\left[1120\right]_{\mathrm{TiB}_2}$ zone axis.

0.011 nm for layer #12. The EELS elemental maps in [Fig.](#page-2-0) $2(d-e)$ $2(d-e)$ $2(d-e)$ offer convincing evidence that these atomic layers are an Al(Mg) solid solution as they are mainly composed of Al, in conjunction with some segregation of Mg. In Fig. $2(e)$, atomic columns are clearly resolved in the Al *L2,*³ map, in direct spatial correlation to the corresponding depleted columns observed in either the core-loss Ti *L2,*³ or B *K* maps. The corresponding HAADF and compositional profiles averaged across the width of the interface further demonstrate this chemical assignment. Given the observed stacking type, *d*-spacings, and compositions, we propose to name such an interfacial complexion (#11–13) as Al-like layers, which also show structural and compositional similarities to the layers (#12–13) observed above Al₃Ti 2DC [\(Fig.](#page-2-0) 2(a1)) in the Al-0.2Al5Ti1B sample.

Reproducible orientation relationships (ORs) are readily found between TiB₂ and α-Al leading to the formation of low-energy interfacial configuration when TiB₂ are potent substrates for the nucleation of α -Al $[13,14,17,40]$ $[13,14,17,40]$ $[13,14,17,40]$ $[13,14,17,40]$. In contrast, such ORs are not observed when TiB₂ gets poisoned by either the segregation of Zr or Si [19–[21\]](#page-5-0). In conjunction with the rejuvenated grain refinement, well-defined ORs have been repeatedly found between TiB₂ and α -Al in Al-0.1Zr-0.2Al5Ti1B-1Mg, with typical examples demonstrated in Fig. 3. By indexing the selected area electron diffraction (SAED) patterns and HRTEM lattice images, the OR1 is identified as: $(0001)_{\text{TiB2}}$ // $(111)_{\text{Al}}$, $[1120]_{\text{TiB}_2}$ // $[011]_{\text{Al}}$, while OR2 is: $(0001)_{\text{TiB2}} \sim 2^{\circ}$ from $(200)_{\text{Al}}$, $[11\overline{2}0]_{\text{TiB}_2}$ // $[011]_{\text{Al}}$. Within experimental errors, they are consistent with previously reported ORs [[13,14,17](#page-5-0),[40,41\]](#page-5-0). The application of Zhang's $\Delta \vec{g}$ theory [\[39](#page-5-0)] to the SAED patterns suggests that both $TiB₂/Al$ interfaces achieve interfacial energy minima under the two ORs from a crystallographic point of view. Specifically, OR1 satisfies the **Rule I** in Ref. [\[39](#page-5-0)] that $\Delta \vec{g}$ is parallel to a rational \vec{g} (Fig. 3(a1)): $\Delta \vec{g}_1 = \vec{g}$ ₍₁₁₁₎*Al*– \vec{g} _{(0001)*TiB2*} is parallel to \vec{g} ₍₀₀₀₁₎*TiB*₂ and also to \vec{g} ₍₁₁₁₎*Al*. For OR2, there exist three $\Delta \vec{g}$ *s* parallel to each other (Fig. 3(b1)), which meets the parallelism criterion **Rule II** in Ref. [\[39](#page-5-0)]. The reappearing ORs satisfying the $\Delta \vec{g}$ criteria strongly suggest that TiB_2 in Al-0.1Zr-0.2Al5Ti1B-1Mg has been reactivated again as nucleation sites .

The atomic-resolution HAADF STEM images in [Fig.](#page-4-0) 4(a[-b\)](#page-4-0) compare the TiB₂/Al₃Ti-2DC/Al and TiB₂/Al-like layers/Al interfaces that obey the OR1 after nucleation and solidification. In both cases, an edge-type misfit dislocation occurs on the Al side to compensate for the lattice mismatch. Structural relaxation appears beneath the dislocation core, specifically at the first Al-rich layer (labelled "layer 1") of less-defined, or "fuzzy" contrast illustrated in [Fig.](#page-4-0) 4[\(c](#page-4-0), [d](#page-4-0)). The *d*-spacing of "layer 1" remains smaller than $d_{\{111\}A}$, but becomes identical to $d_{\{111\}A}$ for all atomic layers upwards. In interfacial regions away from the dislocation ([Fig.](#page-4-0) 4([e,](#page-4-0) [f](#page-4-0))), the FCC-type stacking sequence continues towards the Al matrix. Comparing the interfacial structures to the ones in [Fig.](#page-2-0) 2(a, [c](#page-2-0)), we can attribute the lattice-misfit accommodation during α-Al nucleation to the structural relaxation of the extra layers above Al_3Ti 2DC or of the Al-like layers. On the contrary, the Al $_3$ Ti 2DC does not directly accommodate the lattice misfit as it remains coherent with $TiB₂$ after nucleation ([Fig.](#page-4-0) 4a), in identical fashion to the Al₃Ti 2DC in Fig. $2(a)$ without triggering heterogeneous nucleation. This is different from previous reports where the monolayer Al3Ti 2DC was suggested to initiate dislocation for strain relaxation [\[16,18](#page-5-0)].

The best possible nucleant for α -Al nucleation would be the solid Al itself [[42](#page-5-0)]. Moreover, as indicated by the close characteristics of the Al-like layers to the extra Al-rich layers above the well-known potent Al3Ti 2DC, here we propose that they catalyse the nucleation process by providing a template of a close nature to the Al solid. This mechanism suggests that the Ti₂Zr 2DC, although coherent with TiB₂ as the other 2DCs (Fig. S5), is not potent at all since the ordered layer above does not obey the FCC-stacking pattern. It is important to note that this proposed mechanism assumes that the crystalline adsorbates appear in the melts and are preserved after solidification. This follows the suggestion of Jones's hypernucleation theory [[8](#page-5-0)]. Some evidence from the literature supports this assumption. Firstly, $Al₃Ti$ 2DC and the adsorbates above are structurally comparable to the structures found above the $TiB₂$ embedded in an Al-based glassy matrix after rapid solidification [\[14](#page-5-0)], in which the early-stage nucleation is preserved for observation. If they had developed during cooling in the solid state, we would expect structural differences because of the vastly different dynamics at different cooling rates. Secondly, the adsorbates' ordering degree decays

Fig. 3. Electron microscopy characterisation of BF-TEM, selected area electron diffraction (SAED), and HRTEM showing two well-defined orientation relationships (ORs) between TiB₂ and Al in the sample of Al-0.1Zr-0.2Al5Ti1B-1Mg, with the incident beam parallel to the $[1120]_{\rm Tib_2}$ zone axis. (a) OR1: (0001) $[1120]_{\rm Tib_2}$ // $((\bar{1}1\bar{1})_{\rm Al})$ [011] $_{\rm Al}$; and (b) OR2: (0001) $[11\bar{2}0]_{\rm TB_2}$ // (200)[011] $_{\rm Al}$. The two ORs satisfying either Δ**g**s parallelism criterion [\[39](#page-5-0)] (a) I or (b) II suggest that the poisoned TiB2 particles by Zr segregation have been reactivated for heterogeneous nucleation after the addition of 1 % Mg. Alternatively, OR2 can be treated as the refinement of OR1 by rotating the Al pattern by ~52◦ to meet Δ**g**s parallelism criterion.

Fig. 4. Atomic-resolution HAADF STEM images and the measured interplanar spacings across the TiB2/Al interfaces possessing OR1. (a, c, e) TiB2/Al3Ti-2DC/Al interface in Al-0.2Al5Ti1B; and (b, d, f) TiB₂/Al-like layers/Al interface in Al-0.1Zr-0.2Al5Ti1B-1Mg. (c, d) Enlarged areas containing a misfit dislocation. (e, f)) Enlarged areas free of misfit dislocation on the Al side, with marks of "ABCA…" showing the FCC-type stacking pattern. Note that the incident beam is parallel to [1120]_{TiB2}. After the nucleation of Al solid, the Al₃Ti 2DC monolayer (#9 in (a)) remains coherent with the TiB₂. At the interfaces, local structural relaxation occurs primarily (c) in the first layer (#10 in (a)) above Al₃Ti 2DC or (d) in the first Al-like layer (#9 in (b)), both of which are labelled "layer 1" in (c) and (d).

with distance from the interface, which is a feature typical of liquid ordering [\[36,43](#page-5-0)]. Lastly, the Al-like layers offer a remarkable similarity to the ordered structure at a TiB₂/Al-liquid interface simulated by *ab initio* molecular dynamics above the melting point [[18,35\]](#page-5-0); the ordering process may cease and remain even if eventually nucleation is not triggered on this substrate. Nevertheless, and despite the similarities and correlations highlighted here, we should bear in mind that any structure observed postmortem is by definition not the same as that present in the liquid due to temperature differences, and these results should thus be seen as insights into the solidification process.

Dissolution of Mg in Al causes lattice expansion [[44\]](#page-5-0). With the interfacial segregation of Mg, the lattice of the Al(Mg) solution expands to reduce the lattice misfit with TiB₂, which could also facilitate the formation of Al-like layers and the subsequent nucleation of α -Al. The structural compatibility is further improved when considering thermal

expansion at the nucleation temperature. As demonstrated in Fig. S6, the lattice misfit decreases as the Mg concentration and temperature increase. Therefore, adding Mg into a Al melt with $TiB₂$ inoculation will be beneficial for grain refinement because of both the improved potency (if segregation occurs) and growth restriction effect, a conclusion consistent with the fact that no poisoning by Mg has ever been observed [\[45](#page-5-0)].

In summary, we have demonstrated through casting experiments that adding Mg can revive grain refinement from the Zr-poisoning effect. In the presence of Mg, the poisoned $TiB₂$ particles are re-activated for the heterogeneous nucleation of Al grains, possessing well-defined ORs with the surrounding Al. Dedicated STEM and EELS analyses provide the basis for a proposed underpinning mechanism whereby $TiB₂$ particles are modified by the interfacial segregation of Mg, which allows the dissolution of the poisoning Ti2Zr 2DC and the formation of Al-like layers that act as "good" template to catalyse the nucleation of Al solid.

CRediT authorship contribution statement

Shihao Wang: Writing – original draft, Validation, Methodology, Investigation, Formal analysis, Data curation. **Yun Wang:** Writing – review & editing, Validation, Supervision, Resources, Methodology, Formal analysis, Conceptualization. **Yijie Zhang:** Writing – review & editing, Validation, Investigation, Formal analysis, Data curation. **Feng Wang:** Writing – review & editing, Validation, Methodology, Formal analysis. **Teruo Hashimoto:** Writing – review & editing, Investigation, Data curation. **Xiaorong Zhou:** Writing – review & editing, Resources. **Zhongyun Fan:** Writing – review & editing, Validation, Supervision, Resources, Funding acquisition, Conceptualization. **Quentin Ramasse:** Writing – review & editing, Validation, Supervision, Methodology, Investigation, Funding acquisition, Formal analysis, Data curation.

Declaration of competing interest

The authors declare that they have no known competing financial interests or personal relationships that could have appeared to influence the work reported in this paper.

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Supplementary materials

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